

# Intel® Enpirion® Power Solutions EM2140P01QI 40A PowerSoC

# Step-Down DC-DC Switching Converter with Integrated Inductor, Featuring Digital Control with PMBus<sup>™</sup> v1.2 Compliant Interface

# **Description**

The EM2140 is a fully integrated 40A PowerSoC synchronous buck converter. It features an advanced digital controller, gate drivers, synchronous MOSFET switches, and a high performance inductor. Only input and output filter capacitors and a few small signal components are required for a complete solution. A PMBus version 1.2 compliant interface provides setup, control, and telemetry.

Differential remote sensing and ±0.5% set-point accuracy provides precise regulation over line, load and temperature variation. Very low ripple further reduces accuracy uncertainty to provide best in class static regulation for today's FPGAs, ASICs, processors, and DDR memory devices.

The EM2140 may be used in standalone mode or utilizing the PMBus interface for a high degree of flexibility and programmability. Advanced digital control techniques ensure stability and excellent dynamic performance, and eliminate the need for external compensation components. The PC-based Intel Enpirion Digital Power Configurator provides a user-friendly and easy-to-use interface to the device for communication and configuration.

The EM2140 features high conversion efficiency and superior thermal performance to minimize thermal de-rating limitations, which is key to product reliability and longevity.

#### **Features**

- Integrated inductor, FETs, and digital controller
- Wide 4.5V to 16V V<sub>IN</sub> range
- 0.5V to 1.325V V<sub>OUT</sub> range
- 40A continuous current with no thermal de-rating
- High efficiency in 11mm x 17mm x 6.76mm QFN package
  - $\circ$  90% efficiency at  $V_{IN} = 12V_{,}V_{OUT} = 1.2V_{,}$
- Optimized total solution size of only 365 mm<sup>2</sup>
- Meets all high performance FPGA requirements
   Digital loop for best in class transient response
  - 0.5% set-point over line, load, and temperature
  - Output ripple as low as 10 mV peak-peak
  - Differential remote sensing
  - o Monotonic startup into pre-bias output
  - Optimized FPGA configs stored in NVM
- Programmable through PMBus™
  - $\circ\,V_{\text{OUT}}$  margining, startup and shutdown delays
  - oProgrammable warnings, faults and response
- Ability to operate without PMBus™
  - $\circ RVSET$  resistor for programmable  $V_{\text{OUT}}$
  - oRTUNE resistor for single resistor compensation
- Tracking pin for complex sequencing
- RoHS compliant, MSL level 3, 260°C reflow

# **Applications**

- High performance FPGA supply rails
- ASIC and processor supply rails
- High density double data rate (DDR) memory VDDQ rails

# **Ordering Information**

#### Table 1

Part Number	Supported V <sub>OUT</sub> Range	Package Markings	T <sub>AMBIENT</sub> Rating (°C)	Package Description		
EM2140P01QI	0.5V to 1.325V	M2140	-40 to +85	17 mm x 11 mm x 6.76 mm QFN100 provided in 112 units per tray		
EVB-EM2140P01	0.5V to 1.325V	Evaluation board; 40A single phase				
EVI-EM2COMIF	GUI interface dor	gle				

**Packing and Marking Information**: www.altera.com/support/reliability/packing/rel-packing-and-marking.html

# **Pin Assignments**

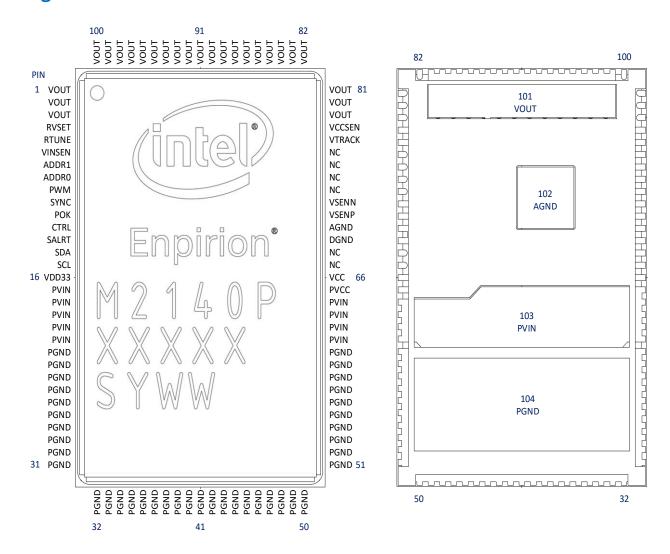


Figure 1: Pin Out Diagram

# **Pin Description**

Table 2

PIN	NAME	I/O	FUNCTION
1,2,3, 79-101	VOUT	Regulated Output	Regulated output voltage. Decouple to PGND with appropriate filter capacitors
4	RVSET	Analog I/O	A resistor from RVSET to AGND; and can be used to program the $V_{\text{OUT}}$ set-point. Using 1% tolerance or better resistor. See Table 8 for more information.
5	RTUNE	Analog I/O	A resistor from RTUNE to AGND; and can be used to tune the transient compensator for the amount of output capacitance. Using 1% tolerance or better resistor. See Table 9 for more information.
6	VINSEN	Analog Input	Single-ended input voltage sense (relative to AGND).
7	ADDR1	Analog I/O	A resistor from ADDR1 to AGND; and can be used to set the PMBus™ address. Use a 1% tolerance or better resistor.
8	ADDR0	Analog I/O	A resistor from ADDR0 to AGND; and can be used to set the PMBus™ address. Use a 1% tolerance or better resistor.
9	PWM	PWM	PWM signal test pin.
10	SYNC	Digital I/O	PWM synchronization signal
11	РОК	Digital I/O	Power OK is selectable as a push-pull output or an open drain transistor for power system state indication. See the Power OK description for details
12	CTRL	Digital Input	PMBus-compatible control pin with programmable functionality. CTRL should never be left floating if enabled in Configuration. The default configuration is for $V_{\text{OUT}}$ to be on with CTRL high (positive edge)
13	SALRT	Digital Output	PMBus™ alert line.
14	SDA	Digital I/O	PMBus™ serial data I/O.
15	SCL	Digital Input	PMBus™ serial clock input.
16	VDD33	Output	3.3V output of the internal LDO. May be used as pull-up supply for PMBus™ pins and CTRL pin.
17-21, 61-64, 103	PVIN	Input Supply	Input supply for MOSFET switches. Decouple to PGND with appropriate filter capacitors. Refer to Recommended Application Circuit section for more details.
22-60, 104	PGND	Ground	Power ground. Ground for MOSFET switches.
65	PVCC	Input Supply	5.0V supply voltage for driver circuitry. Decouple to PGND using a 2.2 $\mu$ F MLCC high quality ceramic capacitor.
66	vcc	Input Supply	5.0V supply voltage for analog circuitry.
67,68, 73-76	NC	NC	No connect. Do not connect to any signal, supply, or ground.
69	DGND	Ground	Digital ground. Connect to AGND pin directly.

PIN	NAME	I/O	FUNCTION
70, 102	AGND	Ground	Analog ground. Connect to system ground plane. Refer to layout section for more details on grounding.
71	VSENP	Analog Input	Differential output voltage sense input (positive).
72	VSENN	Analog Input	Differential output voltage sense input (negative).
77	VTRACK	Analog Input	Voltage tracking reference input if EM2140 is configured for voltage tracking mode. May remain floating if not used. If enabled but not used, connect to VDD33 using a $10k\Omega$ resistor. VTRACK is not enabled in the default configuration.
78	VCCSEN	Analog Input	Single-ended VCC voltage sense (relative to AGND)

# **Absolute Maximum Ratings**

**CAUTION**: Absolute Maximum ratings are stress ratings only. Functional operation beyond the recommended operating conditions is not implied. Stress beyond the absolute maximum ratings may impair device life. Exposure to absolute maximum rated conditions for extended periods may affect device reliability. Voltage measurements are referenced to AGND.

# **Absolute Maximum Pin Ratings**

Table 3

PARAMETER	SYMBOL	MIN	MAX	UNITS
Supply voltage PVIN	PVIN	-0.3	18	V
Supply voltage VCC	VCC	-0.3	5.5	V
VCC ramp time	VCC		20	ms
VDD33	VDD33	-0.3	3.6	V
Digital ground	DGND	-0.3	0.1	V
Power ground	PGND	-0.3	0.3	V
Digital I/O pins	SALRT, POK, SYNC,	-0.3	5.5	V
Digital I/O pins	SCL, SDA, CTRL	-0.3	3.6	V
Analog I/O pins	VINSEN, VCCSEN, ADDR1, ADDR2, RVSET, RTUNE, VTRACK	-0.3	2.0	V
Voltage feedback	VSENP, VSENN	-0.3	2.0	V
PWM pin	PWM	-0.3	5.5	V
Output voltage pins	VOUT	-0.3	1.44	V
DC current on VOUT	VOUT		43	А

# **Absolute Maximum Thermal Ratings**

PARAMETER	CONDITION	MIN	MAX	UNITS
Operating junction temperature			+125	°C
Storage temperature range		-65	+150	°C
Reflow peak body temperature	(10 Sec) MSL3		+260	°C

# **Absolute Maximum ESD Ratings**

PARAMETER	CONDITION	MIN	MAX	UNITS
HBD	All pins; Except VINSEN 1000 V Max	2000		V
CDM; all pins		500		V

# **Recommended Operating Conditions**

#### Table 4

PARAMETER	PINS	MIN	MAX	UNITS
PVIN supply voltage range	PVIN	4.5	16	V
Supply voltage V <sub>CC</sub> & PV <sub>CC</sub>	VCC, PVCC	4.75	5.25	V
Continuous load current	V <sub>OUT</sub>		40	Α

# **Thermal Characteristics**

#### Table 5

PARAMETER	PINS	TYPICAL	UNITS
Thermal shutdown [programmable]	T <sub>SD</sub>	120	°C
Thermal shutdown Hysteresis	T <sub>SDH</sub>	18	°C
Thermal resistance: junction to ambient (0 LFM) (Note1)	$\theta$ JA	8	°C/W
Thermal resistance: junction to case bottom (0 LFM)	θις	1.5	°C/W

**Note1:** Based on 2 oz. external copper layers and proper thermal design in line with EIJ/JEDEC JESD51 standards for high thermal conductivity boards. No top side cooling required.

# **Electrical Characteristics**

 $PV_{IN}$  = 12V and  $V_{CC}$  = 5.0V. The minimum and maximum values are over the operating ambient temperature range (-40°C to 85°C) unless otherwise noted. Typical values are at  $T_A$  = 25°C.

Table 6

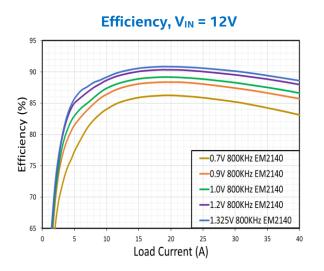
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
TAINFILTER	STINDOL	SUPPLY CHARACTERISTICS	1-1114		1-17-07	ONTS
PVIN supply voltage		JOIT ET CHARACTERISTICS				
range	PVIN		4.5		16	V
PVIN supply quiescent current		Device switching; no load; f <sub>sw</sub> = 800 kHz; V <sub>OUT</sub> = 1.0V		40		mA
Current		Device not switching		1		
VCC supply voltage range	VCC		4.75	5.0	5.25	V
VCC UVLO rising				4.4		V
VCC UVLO falling				4.2		V
		Normal operation; no load; f <sub>sw</sub> = 800 kHz		80		mA
VCC supply current		Idle; communication and telemetry only; no switching		30		mA
		Disabled (V <sub>CC</sub> ≤ 2.8V)		900		μΑ
	INTER	NALLY GENERATED SUPPLY VO	LTAGE	•		
VDD33 voltage range	VDD33		3.0	3.3	3.6	
VDD33 output current					2	mA
		DIGITAL I/O PINS (POK, SYNC)				
Input high voltage			2.0		5.5	V
Input low voltage			0		0.8	V
Output high voltage			2.4		VDD33	V
Output low voltage					0.4	V
Input leakage current					±1	μΑ
Output current - source					2.0	mA
Output current - sink					2.0	mA
		DIGITAL I/O PIN (CTRL)				
Input high voltage			2.0		3.6	V
Input low voltage			-0.3		0.8	V
CTRL response delay (stop)		Configurable polarity; extra turn-off delay configurable (assumes 0 s turn-off delay)		150		μs

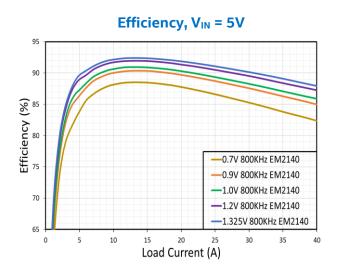
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
CTRL response delay (start)		Configurable polarity; extra turn-on delay configurable (assumes 0 s turn-on delay)		250		μs
н	KADC INPUT	T PINS (VINSEN, VCCSEN, ADDRO	AND ADI	DR1)		
Input voltage			0		1.44	٧
		PWM AND SYNCHRONIZATION				
PWM output voltage - high			2.4			V
PWM output voltage - low					0.4	V
PWM tristate leakage					±1	μΑ
PWM pulse width			30			ns
Resolution				163		ps
Switching frequency – EM2140	f <sub>SW</sub>	With internal oscillator		800		kHz
SYNC frequency range		Percent of nominal switching frequency			±12.5	%
SYNC pulse width			25			ns
0	UTPUT VOL	TAGE SENSE, REPORTING, AND N	<i>MANAGEM</i>	1ENT		
Output voltage adjustment range	EM2140		0.5		1.325	V
Output voltage set-	EM2140	0°C < T <sub>A</sub> < 85°C	-0.5		+0.5	%
point accuracy	EM2140	-40°C < T <sub>A</sub> < 85°C	-1		+1	%
Output set-point resolution	EM2140			1.5		mV
Line regulation				0.007		mV/V
Load regulation				0.07		mV/A
Output voltage startup delay		From V <sub>CC</sub> valid, to start of output voltage ramp, if configured to regulate from power on reset, and TON_DELAY is set to 0.		5		ms
Output voltage ramp delay (TON_DELAY & TOFF_DELAY)		Configurable, no V <sub>OUT</sub> pre-bias condition.	0		500	ms
Vout slew rate				0.5		V/ms
VTRACK ramp rate					2.0	V/ms
VTRACK range		Without resistor divider	0		1.4	V
VTRACK offset voltage				±100		mV

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Ol	JTPUT CURF	RENT SENSE, REPORTING, AND I	MANAGEM	IENT		•
Current sense reporting		25°C < T <sub>A</sub> < 85°C		±1.5		А
accuracy		I <sub>OUT</sub> > 5A, T <sub>A</sub> = 25°C		±1		Α
•	TEMPERATU	RE SENSE, REPORTING, AND MA	NAGEME	NT		•
Temperature reporting accuracy				±5		°C
Resolution				0.22		°C
	FAULT I	MANAGEMENT PROTECTION FEA	ATURES	1	•	
PV <sub>IN</sub> UV threshold				3.96		V
PVIN OV threshold				16.5		V
V <sub>OUT</sub> OV threshold		Percentage of output voltage		115		%
V <sub>OUT</sub> UV threshold		Percentage of output voltage		85		%
I <sub>OUT</sub> OCP		With 50A OCP setting	45		55	Α
OTP threshold				120		°C
OTP hysteresis		Fixed.		85		%
POK threshold		On level		95		%
POK threshold		Off level		90		%
9	SERIAL COM	MUNICATION PMBUS DC CHARA	CTERISTI	CS		
Input voltage – high (VIH)		SCL and SDA	1.11			V
Input voltage – low (VIL)		SCL and SDA			0.8	V
Input leakage current		SCL, SDA, SALRT, and CTRL.	-10		10	μΑ
Output voltage – low (VOL)		SDA and SALRT at rated pull- up current of 20mA.			0.4	V
Nominal bus voltage		SCL, SDA, and SALRT termination voltage.			3.6	V

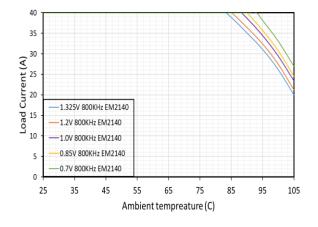
# **Typical Performance Characteristics**

All the performance curves are measured with EM2140 evaluation board at 25°C ambient temperature unless otherwise noted. The output capacitors configuration for the evaluation board is 2 x 470  $\mu$ F (3 m $\Omega$  ESR) + 4 x 100  $\mu$ F (Ceramic) + 4 x 47  $\mu$ F (Ceramic).

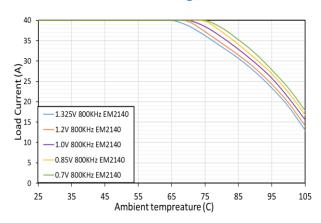




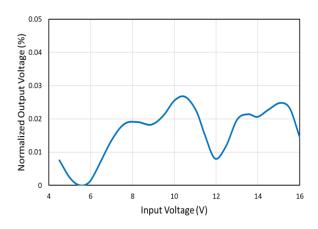
#### Thermal Derating, With Airflow 400 LFM



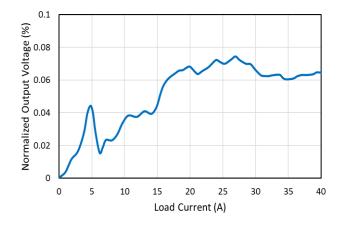
#### Thermal Derating, No Airflow



#### **EM2140 Line Regulation, Vout = 0.9V**

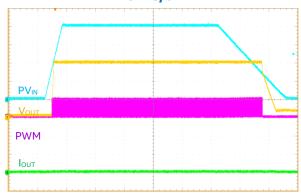


#### EM2140 Load Regulation, V<sub>OUT</sub> = 0.9V



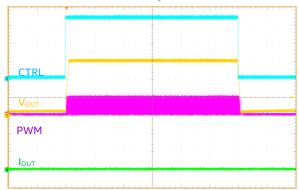
# **Typical Performance Characteristics (Continued)**

# Start-up/Shutdown, PVIN At No Load, 20 ms/div



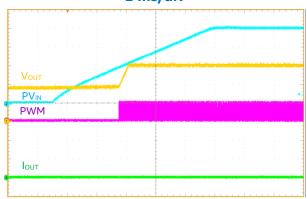
 $PV_{IN}$  and PWM: 3 V/div,  $V_{OUT}$ : 300 mV/div,  $I_{OUT}$ : 20 A/div

## Start-up/Shutdown, CTRL At No Load, 10 ms/div



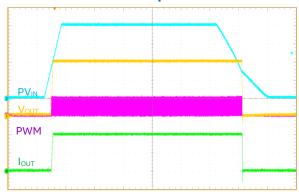
CTRL: 1 V/div, PWM: 3 V/div, V<sub>OUT</sub>: 300 mV/div, I<sub>OUT</sub>: 20 A/div

# Start-up Into 0.6V Pre-Bias With PVIN, 2 ms/div



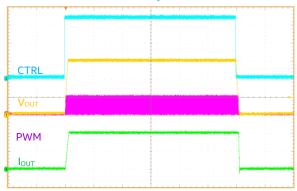
 $PV_{IN}$ : 3 V/div, PWM: 3 V/div,  $V_{OUT}$ : 300 mV/div,  $I_{OUT}$ : 20 A/div

# Start-up/Shutdown, PVIN At 20A Load, 20 ms/div



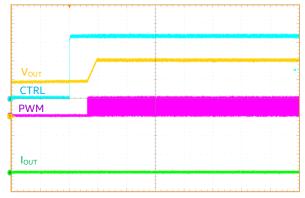
 $PV_{IN}$  and PWM: 3 V/div,  $V_{OUT}$ : 300 mV/div,  $I_{OUT}$ : 20 A/div

# Start-up/Shutdown, CTRL At 20A Load, 10 ms/div



CTRL: 1 V/div, PWM: 3 V/div, V<sub>OUT</sub>: 300 mV/div, I<sub>OUT</sub>: 20 A/div

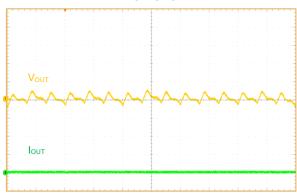
# Start-up Into 0.6V Pre-Bias With CTRL, 2 ms/div



CTRL: 1 V/div, PWM: 3 V/div, V<sub>OUT</sub>: 300 mV/div, I<sub>OUT</sub>: 20 A/div

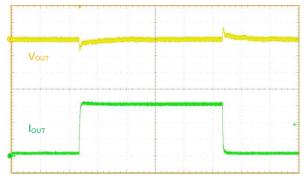
# **Typical Performance Characteristics (Continued)**

#### Output Voltage Ripple, No Load



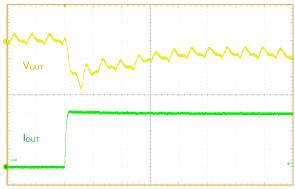
 $V_{IN}$  = 12V,  $V_{OUT}$  = 0.9V 2  $\mu$ s/div,  $V_{OUT}$ : 10 mV/div, 20 MHz bandwidth

# Output Voltage Transient Response, Load Step From 0A To 20A



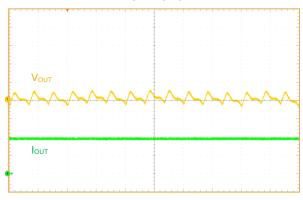
 $V_{IN}$  = 12V,  $V_{OUT}$  = 0.9V, 100 $\mu$ s/div  $V_{OUT}$ : 30 mV/div,  $I_{OUT}$ : 10 A/div, 10 A/ $\mu$ s

## Output Voltage Transient Response, Load Step From 0A To 20A



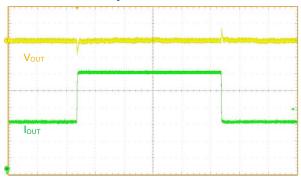
 $V_{IN}$  = 12V,  $V_{OUT}$  = 0.9V, 2 $\mu$ s/div  $V_{OUT}$ : 10 mV/div,  $I_{OUT}$ : 5 A/div, 10 A/ $\mu$ s

#### Output Voltage Ripple, 40A Load



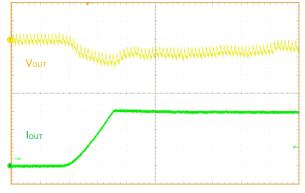
 $V_{IN}$  = 12V,  $V_{OUT}$  = 0.9V 2  $\mu$ s/div,  $V_{OUT}$ : 10 mV/div, 20 MHz bandwidth

#### Output Voltage Transient Response, Load Step From 20A To 40A



 $V_{IN}$  = 12V,  $V_{OUT}$  = 0.9V, 100 $\mu$ s/div  $V_{OUT}$ : 30 mV/div,  $I_{OUT}$ : 10 A/div, 10 A/ $\mu$ s

## Output Voltage Transient Response, Load Step From 0A To 20A



 $V_{IN}$  = 12V,  $V_{OUT}$  = 0.9V, 10 $\mu$ s/div  $V_{OUT}$ : 10 mV/div,  $I_{OUT}$ : 5 A/div, 1 A/ $\mu$ s

## **Functional Block Diagram**

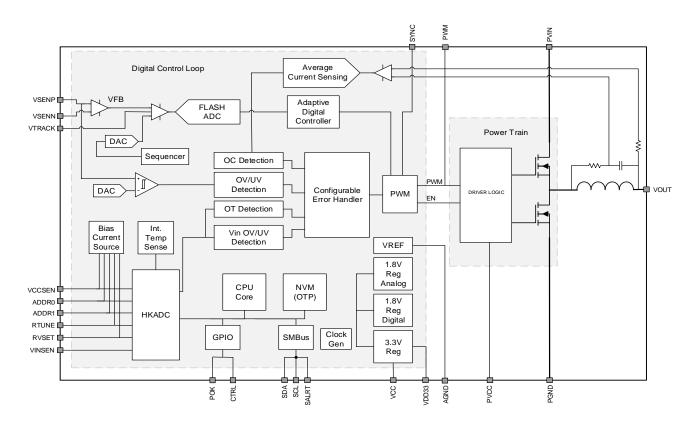


Figure 2: Functional Block Diagram

# **Functional Description**

#### FUNCTIONAL DESCRIPTION: DEFAULT CONFIGURATION

The EM2140 is a single output digital PowerSoC synchronous step-down converter with advanced digital control techniques, capable of supplying up to 40A of continuous output current. The PowerSoC includes integrated power MOSFETs, a high-performance inductor and a digital controller which offers a PMBus version 1.2 compliant interface to support an extensive suite of telemetry, configuration and control commands.

In the default configuration, the EM2140 requires only two resistors to set the output voltage and select from preconfigured digital compensators. This easy-to-use default configuration allows the user to tune the EM2140 to meet the most demanding accuracy and load transient requirements without requiring any programming or digital interface. The following sections describe the default configuration. Refer to the Advanced Configuration section for details on the many ways the EM2140 may be customized and configured through the PMBus interface.

In order to optimize size versus efficiency over a wide range of operating conditions, there are two module variants – a low output voltage variant EM2140 (0.7V  $\leq$  V<sub>OUT</sub>  $\leq$  1.325V) which operates at 800KHz.

The advanced digital control loop works as a voltage-mode controller using a PID-type compensation. The basic structure of the controller is shown in Figure 3. The EM2140 controller features two PID compensators for steady-state operation and fast transient operation. Fast, reliable switching between the different

compensation modes ensures good transient performance and quiet steady state performance. The EM2140 has been pre-programmed with a range of default compensation coefficients which lets the user select the best compensation for the best transient response and stability for the output capacitance of the system.

The EM2140 uses two additional technologies to improve transient performance. First, the EM2140 uses over-sampling techniques to acquire fast, accurate, and continuous information about the output voltage so that the device can react quickly to any changes in output voltage. Second, a non-linear gain adjustment is applied during large load transients to boost the loop gain and reduce the settling time.

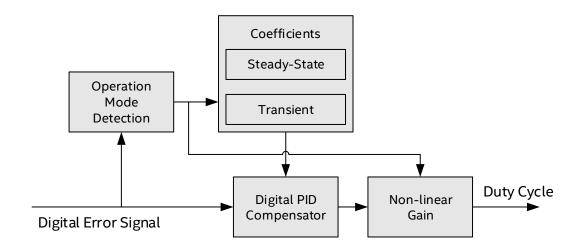


Figure 3: Simplified Block Diagram Of The Digital Compensation

In the default configuration, the EM2140 offers a complete suite of fault warnings and protections. Input and output Under Voltage Lock-Out (UVLO) and Over Voltage Lock-Out (OVLO) conditions are continuously monitored. A dedicated ADC is used to provide fast and accurate current information over the switching period allowing for fast Over-Current Protection (OCP) response. Over Temperature Protection (OTP) is accomplished by direct monitoring of the device's internal temperature.

#### **POWER ON RESET**

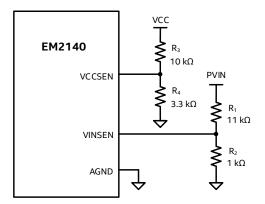
The EM2140 employs an internal power-on-reset (POR) circuit to ensure proper start-up and shut down with a changing supply voltage. Once the VCC supply voltage increases above the POR threshold voltage, the EM2140 begins the internal start-up process. Upon its completion, the device is ready for operation.

Two separate input voltage supplies are necessary to operate, PVIN (4.5V to 16V) and  $V_{CC}$  (4.75V to 5.25V). Both of these voltage rails must be monitored for proper power-up and to protect the power MOSFETs under various input power fault conditions. A voltage divider on each input voltage supply connected to VINSEN for the power rail (PVIN) and VCCSEN for the supply rail (VC) is used for digital monitoring of the supplies.

As illustrated in Figure 4, the values of resistors R1, R2, R3 and R4 are chosen so the internal monitor ADC does not saturate within the appropriate ranges. This allows the EM2140 telemetry to report when the recommended operation voltage has been exceeded.

It is mandatory that the listed resistors values are used in order to ensure proper operation with the EM2140 default configuration. The resistors used must be R1=11 k $\Omega$ , R2=1 k $\Omega$ , R3=10 k $\Omega$  and R4=3.3 k $\Omega$ , using 1% tolerance or better resistors. If these values are not used then the EM2140 will read incorrect values for both PVIN and VCC.

Digital filtering is provided inside the EM2140 but if additional filtering is needed due to high noise on either rail, a capacitor can be connected between each pin (VINSEN & VCCSEN) and ground to maintain high accuracy.



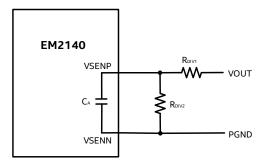
**Figure 4: VINSEN And VCCSEN Input Resistor Dividers** 

The EM2140 also uses the PVIN monitor for input voltage feed-forward, which eliminates variations in the output voltage due to sudden changes in the input voltage supply. It does this by immediately changing the duty cycle to compensate for the input supply variation by normalizing the DC gain of the loop.

#### SETTING THE OUTPUT VOLTAGE

Differential remote sensing provides for precise regulation at the point of load. One of thirty output voltages may be selected in the default configuration, based on a resistor connected to the RVSET pin. At power-up, an internal current source biases the resistor and the voltage is measured by an ADC to decode the Vout selection. Use the RVSET tables (

Table 8) for the details of VOUT selection and RVSET values.



**Figure 5: Output Voltage Sense Circuitry** 

The digital control loop ADC of the low voltage EM2140 supports direct output voltage feedback connection over the entire  $V_{OUT}$  range. For the low output voltage EM2140, a feedback divider is required as shown in Figure 5. The resistor values in Table 7 are required as a function of the output voltage selection. It is mandatory that the listed resistor values are used, use of other values may result in poor regulation performance as these values are expected in the EM2140 default configuration. Resistors with tight tolerances are recommended to maintain output voltage accuracy.

The resistors in the feedback path also form a low-pass filter with the internal capacitor,  $C_A$ , for removing high-frequency disturbances from the sense signals. Place these components as close as possible to the EM2140 for best filtering performance.

**Table 7: Output Voltage Feedback Component** 

Module	V <sub>OUT</sub>	R <sub>DIV1</sub>	R <sub>DIV2</sub>
EM2140	$0.7V \le V_{OUT} \le 1.325V$	2 kΩ	Open

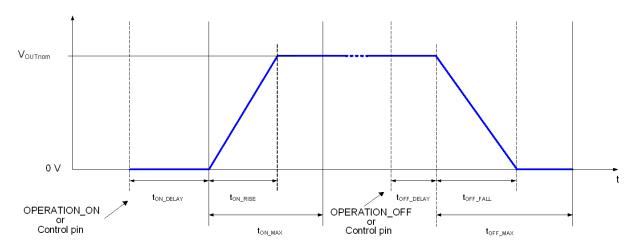
**Table 8: Supported Configuration Voltage Values For EM2140 Output Voltage** 

RVSET Resistor	V <sub>OUT</sub>	External Resistor Divider
OkΩ	0.5V	$R_{1DIV} = 2k\Omega$ , $R_{2DIV} = open$
0.392kΩ	0.55V	$R_{1DIV} = 2k\Omega$ , $R_{2DIV} = open$
0.576kΩ	Reserved	$R_{1DIV} = 2k\Omega$ , $R_{2DIV} = open$
0.787kΩ	Reserved	$R_{1DIV} = 2k\Omega$ , $R_{2DIV} = open$
1.000kΩ	1.325V	$R_{1DIV} = 2k\Omega$ , $R_{2DIV} = open$
1.240kΩ	1.3V	$R_{1DIV} = 2k\Omega$ , $R_{2DIV} = open$
1.500kΩ	1.275V	$R_{1DIV} = 2k\Omega$ , $R_{2DIV} = open$
1.780kΩ	1.25V	$R_{1DIV} = 2k\Omega$ , $R_{2DIV} = open$
2.100kΩ	1.225V	$R_{1DIV} = 2k\Omega$ , $R_{2DIV} = open$
2.430kΩ	1.2V	$R_{1DIV} = 2k\Omega$ , $R_{2DIV} = open$
2.800kΩ	1.175V	$R_{1DIV} = 2k\Omega$ , $R_{2DIV} = open$
3.240kΩ	1.15V	$R_{1DIV} = 2k\Omega$ , $R_{2DIV} = open$
3.740kΩ	1.12V	$R_{1DIV} = 2k\Omega$ , $R_{2DIV} = open$
4.220kΩ	1.1V	$R_{1DIV} = 2k\Omega$ , $R_{2DIV} = open$
4.750kΩ	1.075V	$R_{1DIV} = 2k\Omega$ , $R_{2DIV} = open$
5.360kΩ	1.05V	$R_{1DIV} = 2k\Omega$ , $R_{2DIV} = open$
6.040kΩ	1.03V	$R_{1DIV} = 2k\Omega$ , $R_{2DIV} = open$
6.810kΩ	1.0V	$R_{1DIV} = 2k\Omega$ , $R_{2DIV} = open$
7.680kΩ	0.975V	$R_{1DIV} = 2k\Omega$ , $R_{2DIV} = open$
8.660kΩ	0.95V	$R_{1DIV} = 2k\Omega$ , $R_{2DIV} = open$
9.530kΩ	0.925V	$R_{1DIV} = 2k\Omega$ , $R_{2DIV} = open$
10.500kΩ	0.9V	$R_{1DIV} = 2k\Omega$ , $R_{2DIV} = open$
11.800kΩ	0.875V	$R_{1DIV} = 2k\Omega$ , $R_{2DIV} = open$
13.000kΩ	0.85V	$R_{1DIV} = 2k\Omega$ , $R_{2DIV} = open$
14.300kΩ	0.825V	$R_{1DIV} = 2k\Omega$ , $R_{2DIV} = open$
15.800kΩ	0.8V	$R_{1DIV} = 2k\Omega$ , $R_{2DIV} = open$
17.400kΩ	0.775V	$R_{1DIV} = 2k\Omega$ , $R_{2DIV} = open$
19.100kΩ	0.75V	$R_{1DIV} = 2k\Omega$ , $R_{2DIV} = open$
21.000kΩ	0.725V	$R_{1DIV} = 2k\Omega$ , $R_{2DIV} = open$
23.200kΩ	0.7V	$R_{1DIV} = 2k\Omega$ , $R_{2DIV} = open$

#### ENABLE And OUTPUT START-UP BEHAVIOR

The control pin (CTRL) provides a means to enable normal operation or to shut down the device. When the CTRL pin asserted (high) the device will undergo a normal soft-start. A logic low on this pin will power the device down in a controlled manner. Dedicated pre-biased start-up logic ensures proper start-up of the power converter when the output capacitors are pre-charged to a non-zero output voltage. Closed-loop stability is ensured during this period.

The typical power sequencing, including ramp up/down and delays is shown in Figure 6.



**Figure 6: Power Sequencing** 

#### **POWER OK**

The EM2140 has a power good indicator at its output pin, POK. When de-asserted, POK indicates that the output voltage is below the threshold value, 90% of the programmed output voltage in the default configuration. When asserted, POK indicates that the output is in regulation, and no major faults are present. As a result, POK de-asserts during any serious fault condition where power conversion stops and re-asserts when the output voltage recovers.

The POK indication can be either push-pull or open-drain, selected based upon the PMBus<sup>™</sup> address. For addresses in the range 0x01 to 0x40, the POK signal is a push-pull output and no pull-up resistor is required. For addresses in the range 0x41 to 0x7F, the POK signal is open-drain and may be wire-OR's with other open drain signals with an appropriate pull-up resistor. Table 13 describes the resistor values which are used to set the PMBus address.

#### COMPENSATING THE DIGITAL CONTROL LOOP

To improve the transient performance for a typical point-of-load design, it is common to add output capacitance to the converter. This moves the output LC resonant frequency lower as capacitance increases which results in lower bandwidth, lower phase margin, and longer settling times unless the control loop is compensated for added capacitance.

However, with EM2140 the user does not need to be concerned with, or even understand, the details of control loop compensation techniques. The default configuration allows users to select from preconfigured PID control loop settings (known as compensators) through the use of pin-strapping. A single resistor from the RTUNE pin to AGND informs the EM2140 of the compensator selection.

The selection of the compensator is driven first by the type of output capacitors used, as the ESL and ESR of different capacitor types demands different PID coefficients to optimize transient deviation and recovery

characteristics. An all ceramic output capacitor design requires a different compensator than a design with a combination of ceramic and polymer capacitors, i.e. POSCAP. Table 10 shows several output capacitor part number recommendations.

The five different compensators can then be subdivided into groups of six each whereby the initial capacitance value in the appropriate compensator can be scaled upwards by multiplication factor M to match the additional capacitance.

Table 9:RTUNE configuration table for EM2140

Compensator Description	C <sub>OUT</sub>	RTUNE Resistor	Multiplication	Typical Deviation
	Base	0kΩ	factor (M)	With 15A Load Step ± 5%
Polymer Aluminum (SP-CAP)	2 x Base	0.392kΩ	2	± 3%
and Ceramic MLCC Output	3 x Base	0.576kΩ	3	1 370
Capacitors Base capacitance = 1 x 470µF	4 x Base	0.787kΩ	4	± 1.5%
(Polymer) + 2 x 100μF				± 1.5%
(Ceramic) + 2 x 47μF (Ceramic)	5 x Base	1.000kΩ 1.240kΩ	5	
	6 x Base	-	6	1.50/
	Base	1.500kΩ	1	± 5%
All MLCC Ceramic Output	1.5 x Base	1.780kΩ	1.5	
Capacitors	2 x Base	2.100kΩ	2	± 3%
Base capacitance = 8 x 100μF	3 x Base	2.430kΩ	3	
	4 x Base	2.800kΩ	4	
	4.5 x Base	3.240kΩ	4.5	± 1.5%
	Base	3.740kΩ	1	± 5%
POSCAP and Ceramic MLCC	1.5 x Base	4.220kΩ	1.5	
Output Capacitors	2 x Base	4.750kΩ	2	± 3%
Base capacitance = 4 x 330 μF (POSCAP) + 2 x 100 μF	2.5 x Base	5.360kΩ	2.5	
(Ceramic)	3 x Base	6.040kΩ	3	± 1.5%
	3.5 x Base	6.810kΩ	3.5	
		7.680kΩ		
		8.660kΩ		
		9.530kΩ		
		10.500kΩ		
		11.800kΩ		
Reserved for User		13.000kΩ		
Programmed Compensation Values		14.300kΩ		
3.333		15.800kΩ		
		17.400kΩ		
		19.100kΩ		
		21.000 kΩ		
		23.200 kΩ		

**Table 10: Recommended Output Capacitors** 

Description	Manufacturer	P/N
470μF, 2.5V, ESR 3mΩ SP-CAP	Panasonic	EEFGX0E471R
330μF, 6.3V, ESR 9 mΩ POSCAP	Panasonic	6TPF330M9L
330μF, 2.5V, ESR 9 mΩ POSCAP	Kemet	T520B337M2R5ATE009
100μF, 6.3V, X5R, 1206 Ceramic	Kemet	C1206C107M9PACTU
47μF, 6.3V, X5R 1206 Ceramic	Murata	GRM31CR60J476ME19L

#### **OUTPUT CAPACITOR RECOMMENDATION**

EM2140 is designed for fast transient response and low output ripple noise. The output capacitors should be low ESR polymer, tantalum or ceramic capacitor. **Error! Reference source not found.** shows different output capacitor combinations to optimize the load transient deviation performance. With the Rtune feature, the user can simply scale up the total output capacitance to meet further stringent transient requirement.

Please consult the documentation for your particular FPGA, ASIC, processor, or memory block for the transient and the bulk decoupling capacitor requirements.

#### INPUT CAPACITOR RECOMMENDATION

The EM2140 input should be decoupled with at least three  $22\mu F$  1206 case size and one  $10\mu F$  0805 case size MLCC ceramic capacitors or four  $22\mu F$  MLCC 1206 case size ceramic capacitors. More bulk capacitor may be needed only if there are long inductive traces at the input source or there is not enough source capacitance.

These input decoupling ceramic capacitors can be mounted on the PCB back-side to reduce the solution size. These input filter capacitors should have the appropriate voltage rating for the input voltage on PVIN, and use a X5R, X7R, or equivalent dielectric rating. Y5V or equivalent dielectric formulations must not be used as these lose too much capacitance with frequency, temperature and bias voltage.

The PVCC pin provides power to the gate drive of the internal high/low side power MOSFETs. The VCC pin provides power to the internal digital controller. These two power inputs share the same supply voltage (5V nominal), and should be bypassed with a single  $2.2\mu F$  MLCC capacitor. To avoid switching noise injection from PVCC to VCC, it is recommended a ferrite bead is inserted between PVCC and VCC pins as shown Figure 14.

#### **PROTECTION FEATURES**

The EM2140 offers a complete suite of programmable fault warnings and protections. Input and output Under Voltage Lock-Out (UVLO) and Over Voltage Lock-Out (OVLO) conditions are continuously monitored. A dedicated ADC is used to provide fast and accurate current information during the entire switching period to provide fast Over-Current Protection (OCP) response.

To prevent damage to the load, the EM2140 utilizes an output over-voltage protection circuit. The voltage at VSENP is continuously compared with a configurable threshold using a high-speed analog comparator. If the voltage exceeds the configured threshold, a fault response is generated and the PWM output is turned off.

The output voltage is also sampled, filtered, and compared with an output over-voltage warning threshold. If the output voltage exceeds this threshold, a warning is generated and the preconfigured actions are triggered. The EM2140 also monitors the output voltage with two lower thresholds. If the output voltage is below the under-voltage warning level and above the under-voltage fault level, an output voltage under-voltage warning is triggered. If the output voltage falls below the fault level, a fault event is generated.

Similar to output over and under voltage protection, the EM2140 monitors the input voltage at VINSEN continuously with a configurable threshold. If the input voltage exceeds the over voltage threshold or is below the under voltage threshold, the default response is generated.

Over Temperature Protection (OTP) is based on direct monitoring of the device's internal temperature. If the temperature exceeds the OTP threshold, the device will enter a soft-stop mode slowly ramping the output voltage down until the temperature falls below the default recovery temperature.

The default fault response is zero delay and latch off for most fault conditions. The CTRL pin may be cycled to clear the latch. Table 11 summarizes the default configurations that have been pre-programmed to the device.

Signal	Fault Level	Default Response Type	Delay (ms)	Retries	
Output Over-Voltage	Warning		0	None	
Output Over-voltage	Fault	High-impedance	U	None	
Output Under-Voltage	Warning		0	None	
Output Onder-Voltage	Fault	High-impedance	O	None	
Input Over-Voltage	Warning		0	None	
input Over-voltage	Fault	High-impedance	U		
Input Under Voltage	Warning		0	lan £innia.	
Input Under-Voltage	Fault	High-impedance	0	Infinity	
Over Current	Warning		0	None	
Over-Current	Fault	High-impedance	0		
Internal Over-	Warning		0	Infinity	
Temperature	Fault	Soft Off	0	Infinity	

Table 11: Fault Configuration OverviewTable

#### **FUNCTIONAL DESCRIPTION: ADVANCED CONFIGURATION**

All EM2140 modules are delivered with a pre-programmed default configuration, allowing the module to be powered up without a need to configure the device or even the need for the GUI to be connected. However, a PMBus version 1.2 compliant interface allows access to an extensive suite of digital communication and control commands. This includes configuring the EM2140 for optimum performance, setting various parameters such as output voltage, and monitoring and reporting device behavior including output voltage, output current, and fault responses.

The device may be reconfigured multiple times without storing the configuration into the non-volatile memory (NVM). Any configuration changes will be lost upon power-on reset unless specifically stored into NVM using either STORE\_DEFAULT\_ALL or STORE\_DEFAULT\_CODE PMBus commands. Please see Table 14 for more details.

For RVSET and RTUNE configurations, there is no reprogramming permitted.

After writing a new configuration to NVM, the user may still make changes to the device configuration through the PMBus interface; however, now upon power cycling the device, the stored NVM configuration will be recalled upon power-up rather than the factory default configuration of the EM2140.

The NVM configuration can be stored three times in its entirety. However, the consumption of the available NVM is dynamic, based on the configuration parameters that have actually changed. The unused NVM information is given in the GUI or through the manufacture specific command MFR\_STORE\_PARAMS\_REMAINING.

#### INTEL DIGITAL POWER CONFIGURATOR

The Intel Enpirion Digital Power Configurator is a Graphical User Interface (GUI) software which allows the EM2140 to be controlled via a USB interface to a host computer.

The user can view the power supply's status, I/O voltages, output current and fault conditions detected by the device, program settings to the converter, and issue PMBus commands using the GUI. Most of the parameters (for example, VOUT turn on/off time, protection and fault limits) can be configured and adjusted within the GUI environment. These parameters can also be configured outside of the GUI environment using the relevant PMBus™ commands.

The GUI also allows the user to easily create, modify, test and save a configuration file which may then be used to permanently burn the configuration into NVM within a production test environment.

#### ALTERNATIVE OUTPUT VOLTAGE CONTROL METHODS

In the default configuration, output voltage selection is determined at power-up by the pin-strapped resistor RVSET. This functionality can be disabled using the PMBus command MFR\_PIN\_CONFIG. When RVSET is disabled, the output voltage will be determined by the nominal output voltage setting in the user configuration. The EM2140 supports a subset of the output voltage commands outlined in the PMBus specification. For example, the output voltage can be dynamically changed using the PMBus command VOUT\_COMMAND. When the output is being changed by the PMBus command, power good (POK) remains at a logic high.

### POWER SEQUENCING AND THE CONTROL (CTRL) PIN

Three different configuration options are supported to enable the output voltage. The device can be configured to turn on after an OPERATION\_ON command, via the assertion of the CTRL pin or a combination of both per the PMBus convention. The EM2140 supports power sequencing features including programmable ramp up/down and delays. The typical sequence of events is shown in Figure 6 and follows the PMBus standard. The individual timing values shown in Figure 6 and Figure 7 can be configured using the appropriate configuration setting in Intel Digital Power Configurator GUI.

#### PRE-BIASED START-UP AND SOFT-STOP

In systems with complex power architectures, there may be leakage paths from one supply domain which charge capacitors in another supply domain leading to a pre-biased condition on one or more power supplies. This condition is not idea and can be avoided through careful design, but is generally not harmful. Attempting to discharge the pre-bias is not advised as it may force high current though the leakage path. The EM2140 includes features to enable and disable into pre-biased output capacitors.

If the output capacitors are pre-biased when the EM2140 is enabled, start-up logic in the EM2140 ensures that the output does not pull down the pre-biased voltage and the  $t_{\text{ON\_RISE}}$  timing is preserved. Closed-loop stability is ensured during the entire start-up sequence under all pre-bias conditions.

The EM2140 also supports pre-biased off, in which the output voltage ramp down to a user-defined level  $(V_{OFF\_nom})$  rather than to zero. After receiving the disable command, via PMBus command or the CTRL pin, the EM2140 ramps down the output voltage to the predefined value. Once the value is reached, the output driver into a tristate mode to avoid excessive currents through the leakage path.

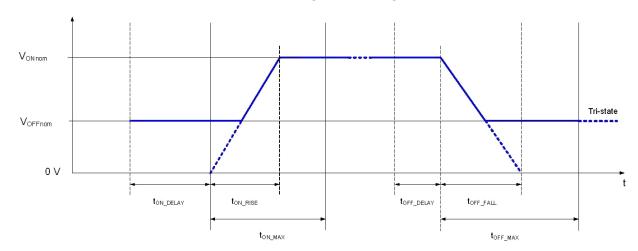


Figure 7: Power Sequencing With Non-Zero Off Voltage

#### **VOLTAGE TRACKING**

The EM2140 can control the output voltage based on the external voltage applied to the VTRACK pin, thus allowing sequencing of the output voltage from an external source. Pre-bias situations are also supported. The VTRACK pin voltage is a single-ended input referenced to analog ground. Tracking mode is disabled by default, but it can be enabled using the GUI software or via the manufacturer-specific PMBus command, MFR\_FEATURES\_CTRL see Table 14.

If VTRACK is not intended to be used, tie the VTRACK pin low or leaving it floating.

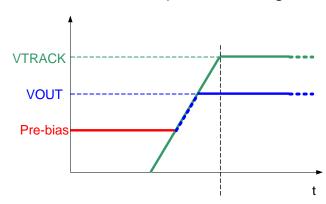
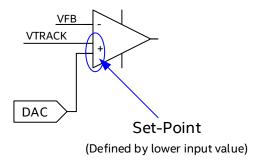


Figure 8: Power Sequencing Using VTRACK With Bias Voltage On VOUT

The set point voltage for the EM2140 is defined by the lower value of the  $V_{OUT}$  setting or an external voltage applied to the VTRACK pin. If the VTRACK voltage rises above the  $V_{OUT}$  set point voltage, then the final output voltage will be limited by the  $V_{OUT}$  setting. If the tracking feature is enabled, but the VTRACK pin is tied low or floating, then the output will never start as the VTRACK pin input is always the lower value and will always be in control. Conversely, if tracking is enabled, but VTRACK is tied high, the output will start but will follow the  $V_{OUT}$  set point, not the VTRACK pin.

If tracking is used for sequencing, it is recommended that the VTRACK signal is kept greater than the  $V_{\text{OUT}}$  voltage. This ensures that the internal  $V_{\text{OUT}}$  set point is used as the final steady-state output voltage and

accuracy is not a function of the externally applied VTARCK voltage. The tracking function will override a programmed pre-bias off level (V<sub>OFF nom</sub>).



**Figure 9: VTRACK Circuitry** 

The following figures demonstrate ratio-metric and simultaneous sequencing of the output voltage, which can be accomplished by applying an appropriate external voltage on the VTRACK pin. When using the VTRACK feature, the sequencing will be ratio-metric as shown in Figure 12 if an external resistor network is used at the VTRACK pin as shown Figure 10. If no external resistors are used, the output sequence is simultaneous as shown in Figure 13.

In the event that a feedback divider is not required, (such as when VOUT  $\leq$  1.4V) but the tracking voltage applied to VTRACK is greater than 1.4V, then a  $2k\Omega$  resistor is required in series with the VTRACK pin to minimize leakage current as shown in Figure 11.

In applications where a voltage divider is required on the output voltage, a voltage divider consisting of the same values is also required for the VTRACK pin.

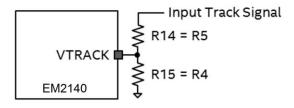


Figure 10: VTRACK Sense Circuitry with Resistor Divider



Figure 11: VTRACK Sense Circuitry (Input > 1.4V)

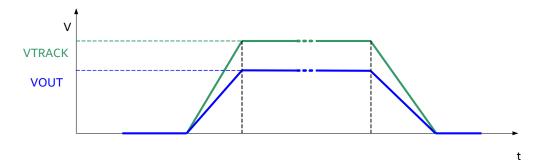


Figure 12: Ratiometric Sequencing Using VTRACK

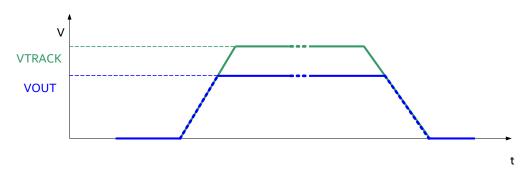


Figure 13: Simultaneous Sequencing Using VTRACK

#### **CLOCK SYNCHRONIZATION**

The EM2140's PWM synchronization feature allows the user to synchronize the switching frequency of multiple devices. The SYNC pin can be configured as an input or an output.

When the SYNC pin is configured as input clock, the external clock need to be available before the EM2140 is enabled. The EM2140 will only lock to the external clock within 1ms after the device is enabled. After 1 ms the device can be re-synchronized to the external clock signal by toggling VOUT or via PMBus MFR\_RESYNC command.

When the SYNC pin is configured as an output clock (sync out), there is no requirement to provide an external clock to allow synchronization.

The EM2140 SYNC functionality maybe configured as an input or an output using Intel's GUI software or via the manufacturer-specific PMBus command, MFR\_PIN\_CONFIG. The default configuration for synchronization control is OFF.

#### TEMPERATURE AND OUTPUT CURRENT MEASUREMENT

The EM2140 temperature sense block provides the device and the system with precision temperature information over a wide range of temperatures (-40°C to +150°C). The temperature sense block measures the digital controller temperature, which will be slightly lower than the powertrain junction temperature.

The EM2140 monitors output current by real-time, temperature compensated DCR current sensing across the inductor. This real-time current waveform is then digitally filtered and averaged for accurate telemetry, fault warning, and management.

Factory calibration has been performed for every EM2140 device to improve measurement accuracy over the full output current range. This allows the EM2140 to correct for DCR manufacturing variations.

For over-current protection, an unfiltered ADC is used in order to minimize delays in protecting the device. Because this measurement is unfiltered, the accuracy of the protection threshold is less than that of the average current reading.

#### PROTECTION AND FAULT RESPONSE

The EM2140 monitors various signals during operation in order to detect fault conditions. Measured and filtered signals are compared to a configurable set of warnings and fault thresholds. In typical usage, a warning sets a status flag, but does not trigger a response; whereas a fault sets a status flag and generates a response. The assertion of the SMBALERT signal can be configured to individual application requirements.

The EM2140 supports a number of different response types depending on the fault detected.

In the default configuration, the EM2140 responds to an over temperature event by ramping down  $V_{OUT}$  in a controlled manner at a slew rate defined by the  $T_{OFF\_FALL}$  value. This response type is termed "Soft-Off". The final state of the output signals depends on the value selected for  $V_{OFFnom}$ .

For all other faults the EM2140 will respond by immediately turning off both the top-side MOSFET and low-side MOSFET. This response type is termed "High-Impedance".

For each fault response, a delay and a retry setting can be configured. If the delay-to-fault value is set to non-zero, the EM2140 will not respond to a fault immediately. Instead it will delay the response by the configured value and then reassesses the signal. If the fault remains present during the delay time, the appropriate response will be triggered. If the fault is no longer present, the previous detection will be disregarded.

If the delay-to-retry value is set to non-zero, the EM2140 will not attempt to restart immediately after fault detection. Instead it will delay the restart by the configured value. If the fault is still present when attempting to restart, the appropriate response will be triggered. If the fault is no longer present, the previous detection will be disregarded. If the delay-to-fault is a non-zero value, then the delay-to-retry value will be a factor of 100 times greater than the delay-to-fault value.

The retry setting, i.e. the number of EM2140 restarts after a fault event, can be configured. This number can be between zero and six. A setting of seven represents infinite retry operation. This setting is commonly known as "Hiccup Mode."

## **PMBus Functionality**

#### INTRODUCTION

The EM2140 supports the PMBus protocol (version 1.2) to enable the use of configuration, monitoring, and fault management features during run-time.

The PMBus host controller is connected to the EM2140 via the PMBus pins (SDA, SCL). A dedicated SMBALERT pin is provided to notify the host that new status information is present.

The EM2140 supports packet correction (PEC) according to the PMBus™ specification.

The EM2140 supports more than 60 PMBus commands in addition to several manufacturer specific commands related to output voltage, faults, telemetry, and more.

The EM2140 provides a PMBus set of synchronous communication lines, with serial clock input (SCL), serial data I/O (SDA), and serial alarm output (SALRT) pins.

The PMBus lines provide 3.6V-tolerance, 1.8V I/O compatibility and open-drain outputs (SDA, SCL and SALRT). The communication lines require external pull-up resistors; typical applications require pull-up resistors on each end of the communication lines (typically values of 10 k $\Omega$  each), connected to VDD33 or an alternative termination voltage. Please refer to the PMBus specification (www.pmbus.org) for full details.

The EM2140 provides configurable behavior for the SALRT pin to allow users to determine which fault or warning conditions to communicate over the SALRT line. The default behavior of the controller ensures that any fault or warning results in the EM2140 SALRT pin going low; the alert behavior is enabled for all faults and warnings. You can deselect any of the faults or warnings so when one of these conditions occur, the SALRT pin is not pulled low.

The EM2140 provides a PMBus compliant power conversion control signal through input CTRL. You can configure input CTRL through the standard PMBus command ON\_OFF\_CONFIG.

By default configuration, the CTRL pin must be pulled high to enable operation and the PMBus command OPERATION is ignored. You can override this function with the ON\_OFF\_CONFIG PMBus command.

Remote measurement and reporting of telemetry information at the power supply level provides feedback on key parameters such as voltages, current levels, temperature, and energy, and allows reporting of information such as faults and warning flags. With this information, data is collected and analyzed while the power supply is in development, such as in the qualification or verification phases, or in the field, and system level interaction such as power capping is implemented. Several telemetry parameters are supported by standard PMBus commands.

The EM2140P supports PMBus output current telemetry through the READ\_IOUT command and reports the low-pass filtered, or DC, output current.

The standard PMBus command READ\_VOUT supports output voltage telemetry.

The standard PMBus command READ VIN supports input voltage telemetry.

The EM2140 supports temperature telemetry and reporting through standardized PMBus commands. READ\_TEMPERATURE\_2 is mapped to the controller die temperature.

The standard PMBus command READ\_FREQUENCY supports switching frequency monitoring. This command returns the scaled frequency of the PWM output in kHz.

The EM2140 supports the LINEAR data format according to the PMBus specification. Note that in accordance with the PMBus specification, all commands related to the output voltage are subject to the VOUT\_MODE settings.

A detailed description of the supported PMBus commands supported by the EM2140 can be found in EM2140 *Application Note – PMBus Commands Guide.* 

#### TIMING AND BUS SPECIFICATION

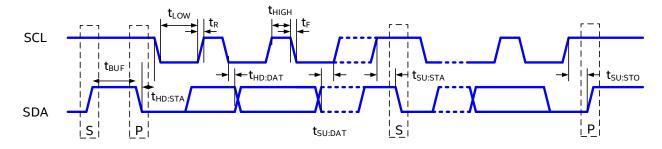


Figure 13: PMBus Timing Diagram

Parameter Symbol Conditions Min Тур Max Units PMBus operation frequency  $f_{SMB}$ 10 100 400 kHz Bus free time between start and stop 1.3 **t**BUF μs Hold time after start condition 0.6 t<sub>HD:STA</sub> μs Repeat start condition setup time 0.6 t<sub>SU:STA</sub> μs Stop condition setup time 0.6 t<sub>SU:STO</sub> μs Data hold time 300 ns t<sub>HD:DAT</sub> 150\* Data setup time ns t<sub>SU:DAT</sub> Clock low time-out **t**TIMEOUT 25 35 ms Clock low period  $t_{\text{LOW}}$ 1.3 μs Clock high period 0.6 t<sub>HIGH</sub> μs Cumulative clock low extend time t<sub>LOW:SEXT</sub> 25 ms Clock or data fall time 300  $t_{\text{F}}$ ns Clock or data rise time 300  $t_R$ ns

**Table 12: EM2140 PMBus Parameters** 

Note: The EM2140 fully complies with PMBus 1.2 specifications for operation up to 100kHz on SCL. The EM2140 may be operated at frequencies up to at least 400kHz on SCL if  $t_{SU:DAT}$  is maintained greater than 150ns.

#### ADDRESS SELECTION VIA EXTERNAL RESISTORS

The PMBus protocol uses a 7-bit device address to identify different devices connected to the bus. This address can be selected via external resistors connected to the ADDRx pins.

The resistor values are sensed using the internal ADC during the initialization phase and the appropriate PMBus address is selected. Note that the respective circuitry is only active during the initialization phase; hence

no DC voltage can be measured at the pins. The supported PMBus addresses and the values of the respective required resistors are listed in Table 13.

**Table 13: Supported Resistor Values For PMBus Address Selection** 

Address (hex)	ADDR1	ADDR0 Ω	Address (hex)	ADDR1	ADDR0 Ω	Address (hex)	ADDR1	ADDR0 Ω
0x40	0	0	0x2B	1.2 k	12 k	0x56	3.9 k	4.7 k
0x01*	0	680	0x2C	1.2 k	15 k	0x57	3.9 k	5.6 k
0x02*	0	1.2 k	0x2D	1.2 k	18 k	0x58	3.9 k	6.8 k
0x03*	0	1.8 k	0x2E	1.2 k	22 k	0x59	3.9 k	8.2 k
0x04*	0	2.7 k	0x2F	1.2 k	27 k	0x5A	3.9 k	10 k
0x05*	0	3.9 k	0x30	1.8 k	0	0x5B	3.9 k	12 k
0x06*	0	4.7 k	0x31	1.8 k	680	0x5C	3.9 k	15 k
0x07*	0	5.6 k	0x32	1.8 k	1.2 k	0x5D	3.9 k	18 k
0x08*	0	6.8 k	0x33	1.8 k	1.8 k	0x5E	3.9 k	22 k
0x09	0	8.2 k	0x34	1.8 k	2.7 k	0x5F	3.9 k	27 k
0x0A	0	10 k	0x35	1.8 k	3.9 k	0x60	4.7 k	0
0x0B	0	12 k	0x36	1.8 k	4.7 k	0x61*	4.7 k	680
0x0C*	0	15 k	0x37*	1.8 k	5.6 k	0x62	4.7 k	1.2 k
0x0D	0	18 k	0x38	1.8 k	6.8 k	0x63	4.7 k	1.8 k
0x0E	0	22 k	0x39	1.8 k	8.2 k	0x64	4.7 k	2.7 k
0x0F	0	27 k	0x3A	1.8 k	10 k	0x65	4.7 k	3.9 k
0x10	680	0	0x3B	1.8 k	12 k	0x66	4.7 k	4.7 k
0x11	680	680	0x3C	1.8 k	15 k	0x67	4.7 k	5.6 k
0x12	680	1.2 k	0x3D	1.8 k	18 k	0x68	4.7 k	6.8 k
0x13	680	1.8 k	0x3E	1.8 k	22 k	0x69	4.7 k	8.2 k
0x14	680	2.7 k	0x3F	1.8 k	27 k	0x6A	4.7 k	10 k
0x15	680	3.9 k	0x40	2.7 k	0	0x6B	4.7 k	12 k
0x16	680	4.7 k	0x41	2.7 k	680	0x6C	4.7 k	15 k
0x17	680	5.6 k	0x42	2.7 k	1.2 k	0x6D	4.7 k	18 k
0x18	680	6.8 k	0x43	2.7 k	1.8 k	0x6E	4.7 k	22 k
0x19	680	8.2 k	0x44	2.7 k	2.7 k	0x6F	4.7 k	27 k
0x1A	680	10 k	0x45	2.7 k	3.9 k	0x70	5.6 k	0
0x1B	680	12 k	0x46	2.7 k	4.7 k	0x71	5.6 k	680
0x1C	680	15 k	0x47	2.7 k	5.6 k	0x72	5.6 k	1.2 k
0x1D	680	18 k	0x48	2.7 k	6.8 k	0x73	5.6 k	1.8 k

Address (hex)	ADDR1 Ω	ADDR0 Ω	Address (hex)	ADDR1 Ω	ADDR0 Ω	Address (hex)	ADDR1 Ω	ADDR0 Ω
0x1E	680	22 k	0x49	2.7 k	8.2 k	0x74	5.6 k	2.7 k
0x1F	680	27 k	0x4A	2.7 k	10 k	0x75	5.6 k	3.9 k
0x20	1.2 k	0	0x4B	2.7 k	12 k	0x76	5.6 k	4.7 k
0x21	1.2 k	680	0x4C	2.7 k	15 k	0x77	5.6 k	5.6 k
0x22	1.2 k	1.2 k	0x4D	2.7 k	18 k	0x78*	5.6 k	6.8 k
0x23	1.2 k	1.8 k	0x4E	2.7 k	22 k	0x79*	5.6 k	8.2 k
0x24	1.2 k	2.7 k	0x4F	2.7 k	27 k	0x7A*	5.6 k	10 k
0x25	1.2 k	3.9 k	0x50	3.9 k	0	0x7B*	5.6 k	12 k
0x26	1.2 k	4.7 k	0x51	3.9 k	680	0x7C*	5.6 k	15 k
0x27	1.2 k	5.6 k	0x52	3.9 k	1.2 k	0x7D*	5.6 k	18 k
0x28*	1.2 k	6.8 k	0x53	3.9 k	1.8 k	0x7E*	5.6 k	22 k
0x29	1.2 k	8.2 k	0x54	3.9 k	2.7 k	0x7F*	5.6 k	27 k
0x2A	1.2 k	10 k	0x55	3.9 k	3.9 k			

**Note2**: The gray-highlighted addresses with an asterisks are reserved by the SMBus specification.

#### **PMBUS COMMANDS**

A detailed description of the PMBus commands supported by the EM2140 can be found in a separate document - *EM2140 PMBus Commands Guide*. Below, Table 14 lists of all supported PMBus commands.

**Table 14: List Of Supported PMBus Commands** 

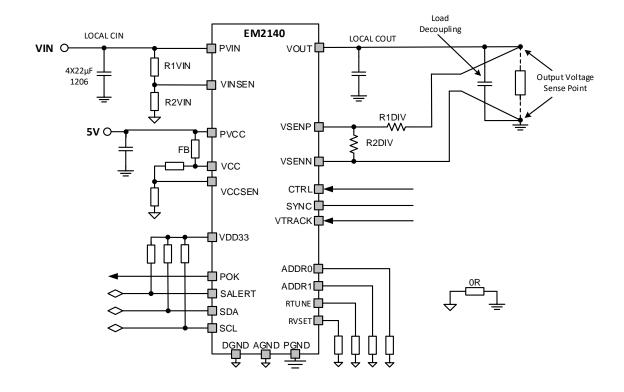
Command Code	PMBus Parameter	Description
01 <sub>HEX</sub>	OPERATION	On/off command
02 <sub>HEX</sub>	ON_OFF_CONFIG	On/off configuration
03нех	CLEAR_FAULTS	Clear status information
10 <sub>HEX</sub>	WRITE_PROTECT	Protect against changes
11 <sub>HEX</sub>	STORE_DEFAULT_ALL	Copy entire memory into OTP
12 <sub>HEX</sub>	RESTORE_DEFAULT_ALL	Copy entire memory from OTP
13 <sub>HEX</sub>	STORE_DEFAULT_CODE	Copy single parameter into OTP
14 <sub>HEX</sub>	RESTORE_DEFAULT_CODE	Copy single parameter from OTP
20 <sub>HEX</sub>	VOUT_MODE (Note3)	Exponent of the VOUT_COMMAND value
21 <sub>HEX</sub>	VOUT_COMMAND	Set output voltage
22 <sub>HEX</sub>	VOUT_TRIM	Apply a fixed offset voltage
23 <sub>нех</sub>	VOUT_CAL_OFFSET	Apply a fixed offset voltage

Command Code	PMBus Parameter	Description
25 <sub>HEX</sub>	VOUT_MARGIN_HIGH	Sets maximum value
26нех	VOUT_MARGIN_LOW	Sets minimum value
29 <sub>HEX</sub>	VOUT_SCALE_LOOP	Scalar for output voltage divider
2A <sub>HEX</sub>	VOUT_SCALE_MONITOR	Scalar for read-back with output voltage divide
35 <sub>HEX</sub>	VIN_ON	Input voltage turn on threshold
36 <sub>HEX</sub>	VIN_OFF	Input voltage turn off threshold
38 <sub>HEX</sub>	IOUT_CAL_GAIN	Sets ratio of sensed voltage to inductor currer
39 <sub>HEX</sub>	IOUT_CAL_OFFSET	Compensation of current sense offset
40 <sub>HEX</sub>	VOUT_OV_FAULT_LIMIT	Over-voltage fault limit
41 <sub>HEX</sub>	VOUT_OV_FAULT_RESPONSE	Over-voltage fault response
42 <sub>HEX</sub>	VOUT_OV_WARN_LIMIT	Over-voltage warning level
43 <sub>HEX</sub>	VOUT_UV_WARN_LIMIT	Under-voltage warning level
44 <sub>HEX</sub>	VOUT_UV_FAULT_LIMIT	Under-voltage fault level
45нех	VOUT_UV_FAULT_RESPONSE	Under-voltage fault response
55 <sub>HEX</sub>	VIN_OV_FAULT_LIMIT	Over-voltage fault limit
56нех	VIN_OV_FAULT_RESPONSE	Over-voltage fault response
57 <sub>HEX</sub>	VIN_OV_WARN_LIMIT	Over-voltage warning level
58 <sub>HEX</sub>	VIN_UV_WARN_LIMIT	Under-voltage warning level
59 <sub>HEX</sub>	VIN_UV_FAULT_LIMIT	Under-voltage fault level
5A <sub>HEX</sub>	VIN_UV_FAULT_RESPONSE	Under-voltage fault response
5E <sub>HEX</sub>	POWER_GOOD_ON	Power good on threshold
5F <sub>HEX</sub>	POWER_GOOD_OFF	Power good off threshold
60нех	TON_DELAY	Turn-on delay
61 <sub>HEX</sub>	TON_RISE	Turn-on rise time
62 <sub>HEX</sub>	TON_MAX_FAULT_LIMIT	Turn-on maximum fault time
64 <sub>HEX</sub>	TOFF_DELAY	Turn-off delay
65нех	TOFF_FALL	Turn-off fall time
66 <sub>HEX</sub>	TOFF_MAX_WARN_LIMIT	Turn-off maximum warning time
78 <sub>HEX</sub>	STATUS_BYTE	Unit status byte
79 <sub>HEX</sub>	STATUS_WORD	Unit status word
7A <sub>HEX</sub>	STATUS_VOUT	Output voltage status
7B <sub>HEX</sub>	STATUS_IOUT	Output current status

Command Code	PMBus Parameter	Description
7C <sub>HEX</sub>	STATUS_INPUT	Input status
7E <sub>HEX</sub>	STATUS_CML	Communication and memory status
80 <sub>HEX</sub>	STATUS_MFR_SPECIFIC	Manufacturer specific status
88нех	READ_VIN	Reads input voltage
8B <sub>HEX</sub>	READ_VOUT	Reads output voltage
8C <sub>HEX</sub>	READ_IOUT	Reads output current
8E <sub>HEX</sub>	READ_TEMPERATURE	Reads temperature
95нех	READ_FREQUENCY	Reads switching frequency
96нех	READ_POUT	Reads output power
98 <sub>HEX</sub>	PMBUS™_REVISION	PMBus <sup>™</sup> revision
99 <sub>HEX</sub>	MFR_ID	Manufacturer ID
9A <sub>HEX</sub>	MFR_MODEL	Manufacturer model identifier
9Внех	MFR_REVISION	Manufacturer product revision
9E <sub>HEX</sub>	MFR_SERIAL	Serial number
A0 <sub>HEX</sub>	MFR_VIN_MIN	Minimum input voltage
A4 <sub>HEX</sub>	MFR_VOUT_MIN	Minimum output voltage
D0 <sub>HEX</sub>	MFR_SPECIFIC_00	Write word (once) / Read word – 2 bytes
D1 <sub>HEX</sub>	MFR_SPECIFIC_01	Write word / read word – 12 bytes
D2 <sub>HEX</sub>	MFR_READ_VCC	Reads VCC voltage
D3 <sub>HEX</sub>	MFR_RESYNC	Active RESYNC
DA <sub>HEX</sub>	MFR_RTUNE_CONFIG	Gets/sets RTUNE settings
DB <sub>HEX</sub>	MFR_VOUT_MARGIN_HIGH	Gets/sets Margin High
DC <sub>HEX</sub>	MFR_VOUT_MARGIN_LOW	Gets/sets Margin Low
DD <sub>HEX</sub>	MFR_RTUNE_INDEX	Returns index derived from resistor detected on RTUNE pin
DE <sub>HEX</sub>	MFR_RVSET_INDEX	Returns index derived from resistor detected on RVSET pin
E0 <sub>HEX</sub>	MFR_VOUT_OFF	Sets the target turn-off voltage
E2 <sub>HEX</sub>	MFR_OT_FAULT_LIMIT	Over-temperature fault level
E3 <sub>HEX</sub>	MFR_OT_WARN_LIMIT	Over-temperature warning level
E5 <sub>HEX</sub>	MFR_OT_FAULT_RESPONSE	Over-temperature fault response
Е6нех	MFR_TEMP_ON	Over-temperature on level

Command Code	PMBus Parameter	Description
E7 <sub>HEX</sub>	MFR_PIN_CONFIG	Enable/disable – RTUNE, RVSET, VTRACK and SYNC
E9 <sub>HEX</sub>	MFR_STORE_CONFIG_ADDR_READ	Reads a configuration value
EA <sub>HEX</sub>	MFR_STORE_PARAMS_REMAINING	Number of STORE_DEFAULT_ALL commands remaining
EB <sub>HEX</sub>	MFR_STORE_CONFIGS_REMAINING	Number of full configurations remaining
ECHEX	MFR_STORE_CONFIG_BEGIN	Commence programming of OTP
ED <sub>HEX</sub>	MFR_STORE_CONFIG_ADDR_DATA	Program a configuration value
EE <sub>HEX</sub>	MFR_STORE_CONFIG_END	Completed programming of OTP

Note3: VOUT\_ MODE is read only for the EM2140



**Figure 14: Recommended Application Circuit** 

## **Layout Recommendations**

**Recommendation 1:** It is highly recommended to use separate nets for AGND and PGND and connecting them through a  $0\Omega$  resistor or a short. This method helps with ground management and prevents the noise from the Power Ground disturbing the more sensitive Analog ("Signal") Ground.

**Recommendation 2:** It is good practice to minimize the PGND loop. Whenever possible the input and output loops should close to the same point, which is the ground of the EM2140 module. Module decoupling ceramic capacitors are to be placed as close as possible to the module in order to contain the switching noise in the smallest possible loops and to improve PVIN decoupling by minimizing the series parasitic inductance of the PVIN traces. For achieving this goal, it helps to place decoupling capacitors on the same side as the module since VIAs are generally more inductive, thus reducing the effectiveness of the decoupling. Of course, bulk and load high frequency decoupling should be placed closer to the load.

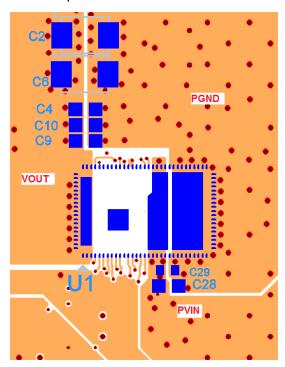


Figure 15: Top Layer Layout With Critical Components Only

**Recommendation 3:** It is good practice to place the other small components needed by the EM2140 on the opposite side of the board, in order to avoid cutting the power planes on the module side. Since the EM2140 heat is evacuated mostly through the PCB, this will also help with heat dissipation; wide copper planes under the module can also help with cooling. The PVIN copper plane should not be neglected as it helps spread the heat from the high side FET.

**Recommendation 4**: It is recommended that at least below the EM2140 module, the next layers to the surface (2 and n-1) be solid ground planes, which provides shielding and lower the ground impedance at the module level. AGND should be also routed as a copper plane, in order to reduce the ground impedance and reduce noise injection.

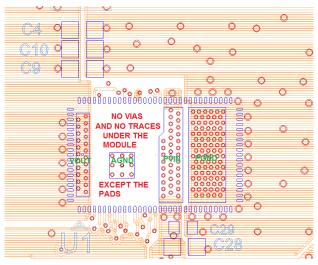


Figure 16: VIAs in The Power Pads

**Recommendation 5**: In order to better spread the current and the heat through the inner layers, arrays of VIAs should be placed in the power pads. 10mils diameter is a good size for the plated in-pad VIAs. It is critical that through VIAs should not be placed by any means elsewhere under the module; the non-pad area around AGND is VIA keep out area.

**Recommendation 6**: All other signal and LDO decoupling capacitors should be placed as close as possible to the terminal they are decoupling, while the AGND connection should be done through VIAs to the AGND plane.

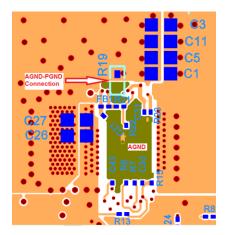


Figure 17: Backside Decoupling

All Signal Decoupling Go To The Bottom AGND Plane And Get Connected To The EM2140 Module AGND Through The AGND In-PAD VIAs (Again, No Other VIAs Are Allowed In That Area)

**Recommendation 7**: Figure 20 also shows the  $0\Omega$  resistor that connects AGND to PGND. The recommended connecting point, as shown, is to a quiet PGND  $\rightarrow$  the output capacitors PGND.

**Recommendation 8:** Differential remote sense should be routed as much as possible as a differential pair, on an inner layer, preferably shielded by a ground plane.

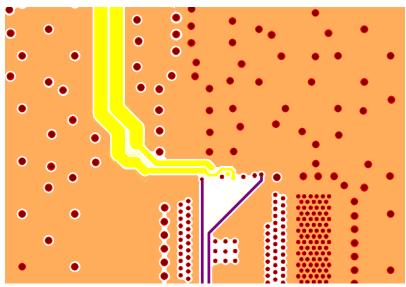
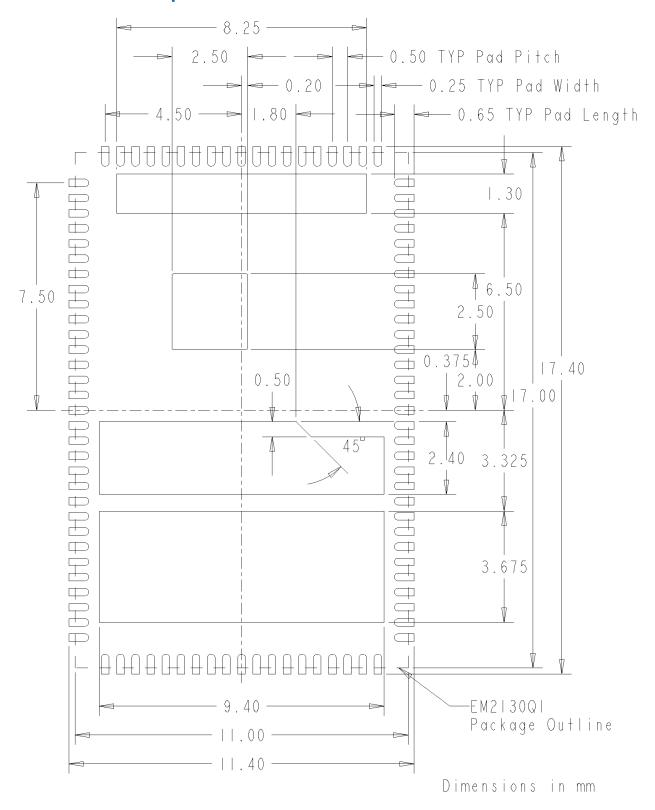


Figure 18: Remote Sense Routing On An Inner Layer (Highlighted, Yellow)

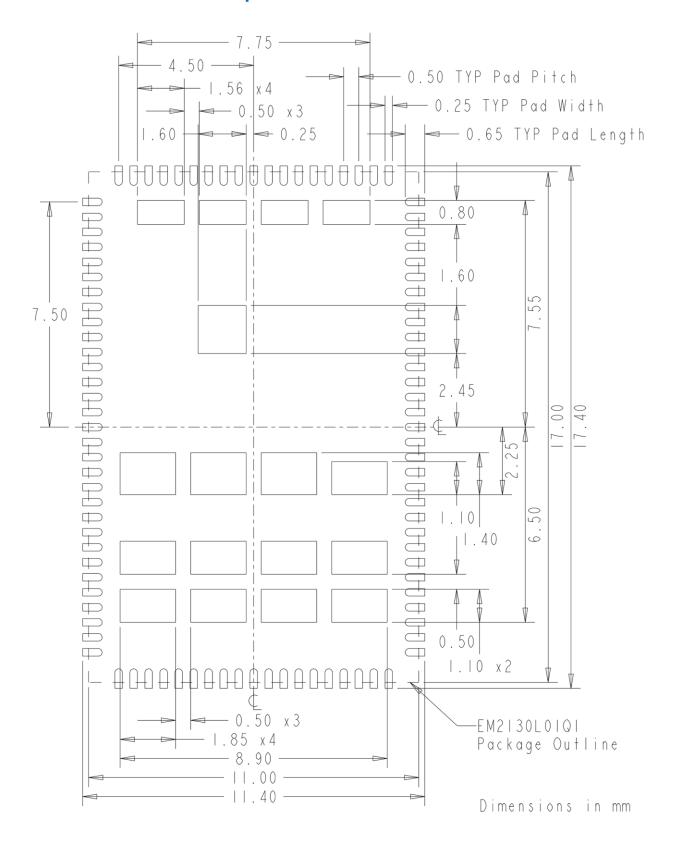
**Recommendation 9**: If the design allows it, stitching VIAs can be used on the power planes, close to the module in order to help with cooling. This is a thermal consideration and does not matter much for the electrical design.

# **Recommended PCB Footprint**



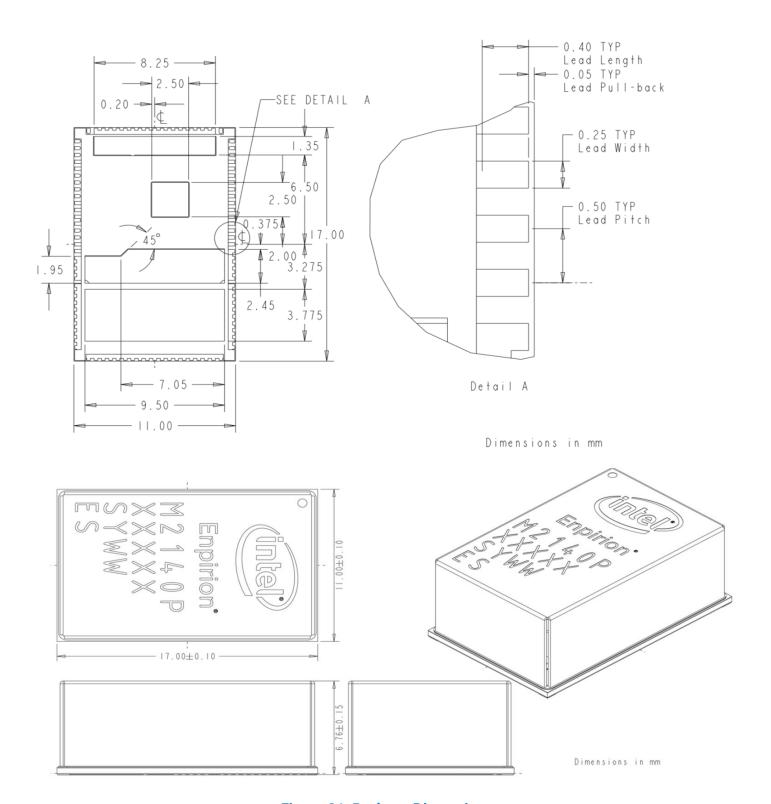
**Figure 19: Recommended PCB Footprint** 

# **Recommended Solder Stencil Aperture**



**Figure 20: Recommended Solder Stencil Aperture** 

# **Package Dimensions**



**Figure 21: Package Dimensions** 

# **Tray Information**

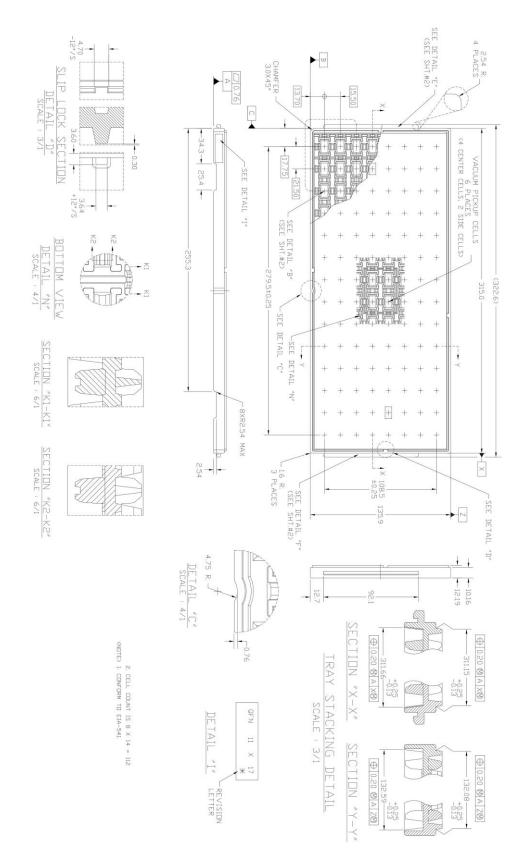


Figure 22: Tray Information 1/2

# **Tray Information (Continued)**

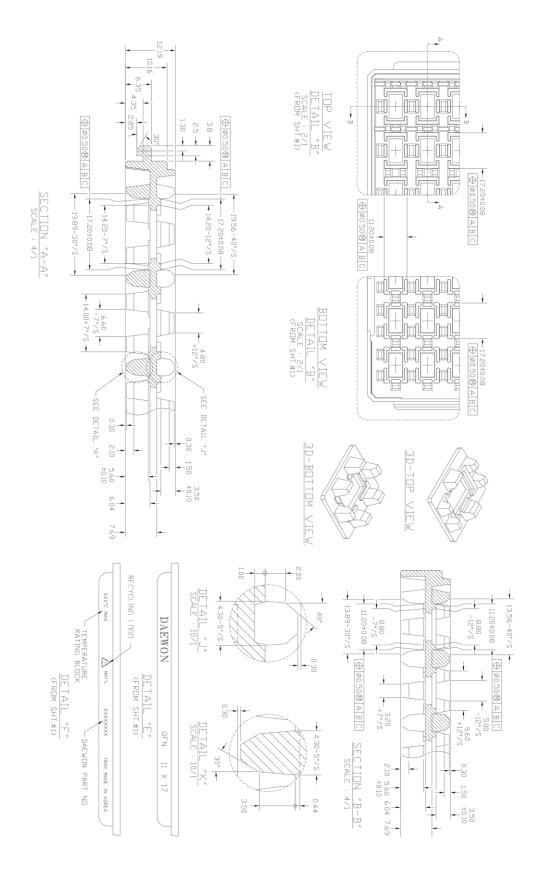


Figure 23: Tray Information 2/2

# **Revision History**

Rev	Date	Change(s)
Α	March-17	Initial Release
В	May-17	Added Rtune table for EM2140 Removed old Table 12 and Figure 7, updated the Output Capacitor Recommendation section. Updated for new POK functionality.

Data Sheet   Intel Enpirion Power Solutions: EM2140
Where to Get More Information
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